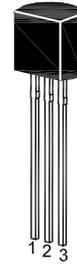


2SC2383-HAF

NPN Silicon Epitaxial Planar Transistor

Features

- The transistor is subdivided into three groups, R, O and Y, according to its DC current gain
- On special request, these transistors can be manufactured in different pin configurations
- Halogen and Antimony Free(HAF), RoHS compliant



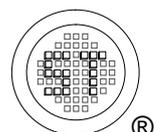
1. Emitter 2. Collector 3. Base
TO-92 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	160	V
Collector Emitter Voltage	V_{CEO}	160	V
Emitter Base Voltage	V_{EBO}	6	V
Collector Current	I_C	1	A
Base Current	I_B	0.5	A
Collector Power Dissipation	P_{tot}	900	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Thermal Characteristics

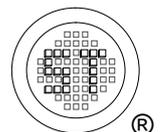
Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	139	$^\circ\text{C/W}$



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Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at $V_{CE} = 5\text{ V}$, $I_C = 200\text{ mA}$	Current Gain Group R O Y	h_{FE}	60	-	120	-
		h_{FE}	100	-	200	-
		h_{FE}	160	-	320	-
Collector Base Cutoff Current at $V_{CB} = 150\text{ V}$	I_{CBO}	-	-	1	μA	
Emitter Base Cutoff Current at $V_{EB} = 6\text{ V}$	I_{EBO}	-	-	1	μA	
Collector Base Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CBO}$	160	-	-	V	
Collector Emitter Breakdown Voltage at $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	160	-	-	V	
Emitter Base Breakdown Voltage at $I_E = 1\text{ mA}$	$V_{(BR)EBO}$	6	-	-	V	
Collector Emitter Saturation Voltage at $I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$	$V_{CE(sat)}$	-	-	1.5	V	
Base Emitter Voltage at $I_C = 5\text{ mA}$, $V_{CE} = 5\text{ V}$	V_{BE}	0.45	-	0.75	V	
Transition Frequency at $V_{CE} = 5\text{ V}$, $I_C = 200\text{ mA}$	f_T	20	100	-	MHz	
Collector Output Capacitance at $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	-	20	pF	



2SC2383-HAF

Electrical Characteristics Curves

Fig. 1 Output Characteristics Curve

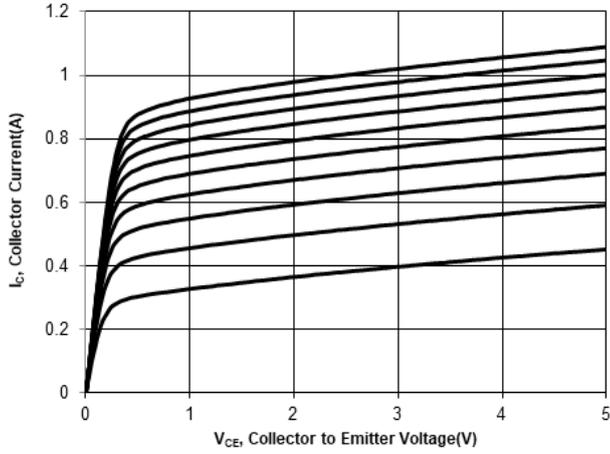


Fig. 2 Output Characteristics Curve

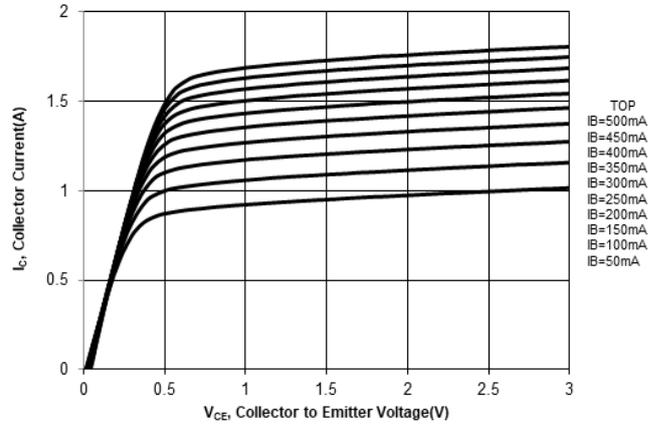


Fig. 3 Collector Current Vs. Base to Emitter Voltage

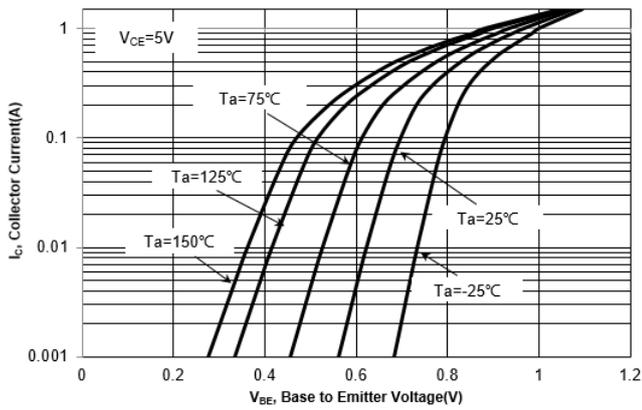
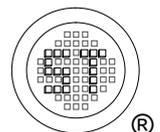
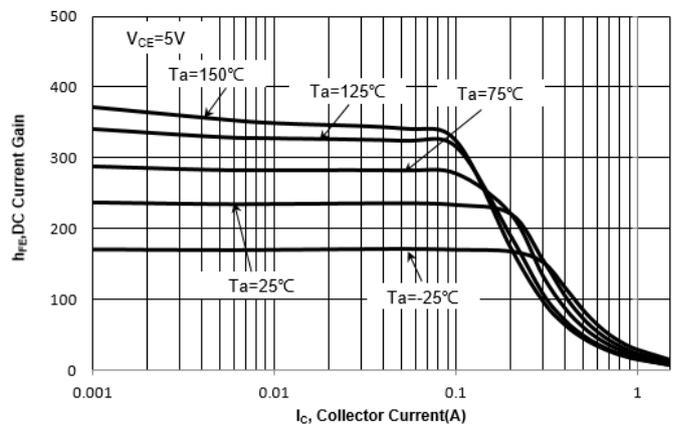


Fig. 4 h_{FE} , DC Current Gain vs. Collector Current



Electrical Characteristics Curves

Fig. 5 $V_{BE(SAT)}$ vs. Collector Current

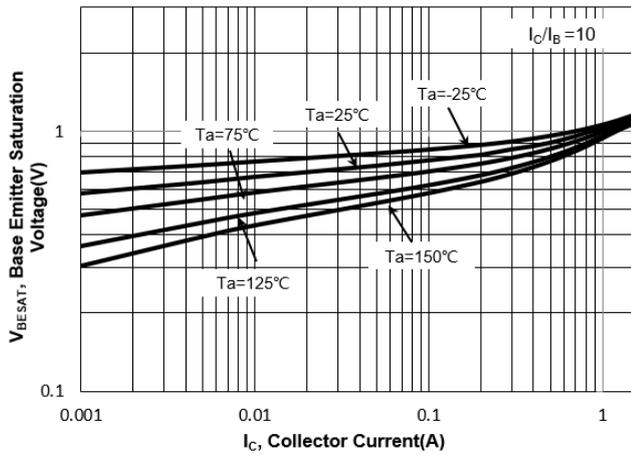


Fig. 6 $V_{CE(SAT)}$ vs. Collector Current

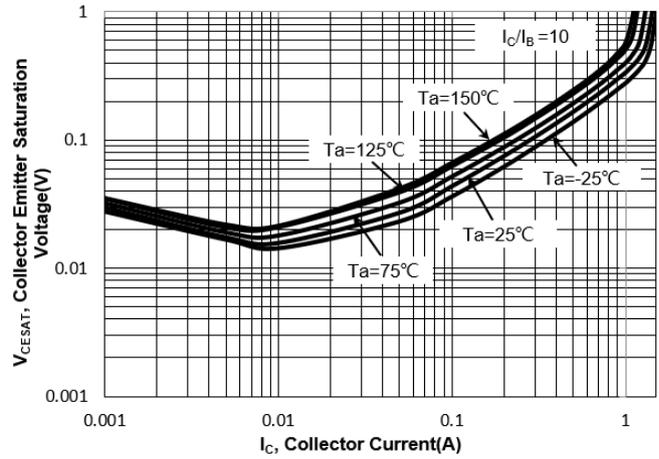


Fig. 7 Junction Capacitance

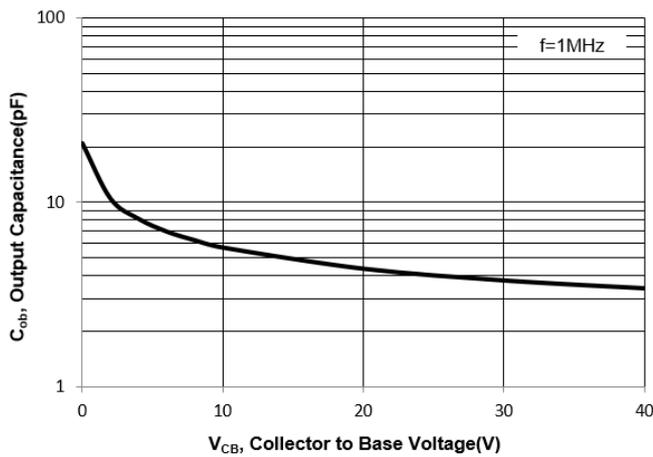
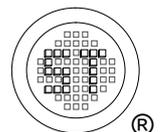
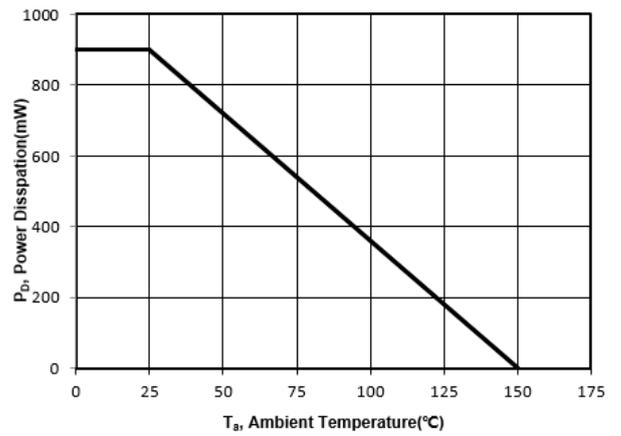
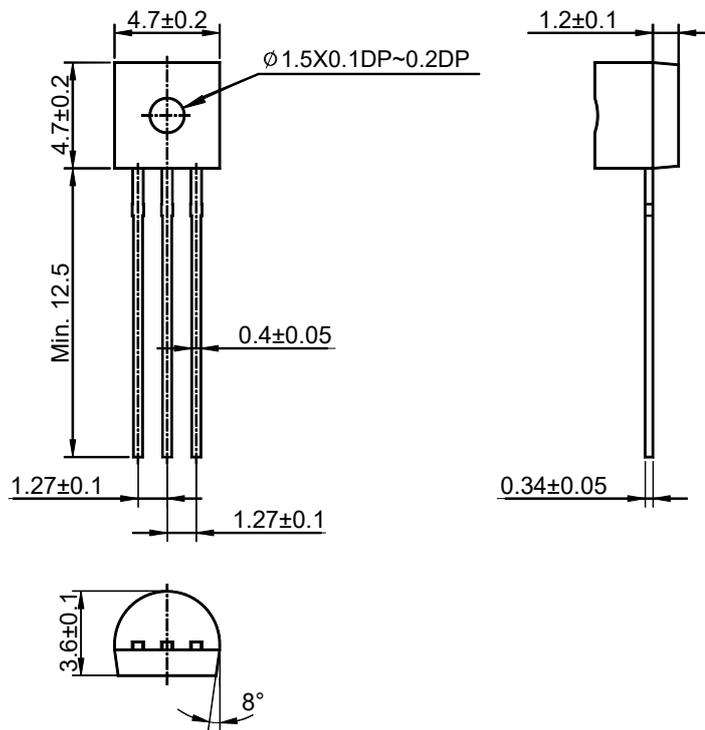


Fig 8. Power Derating Curve



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TO-92 Package Outline (Dimensions in millimeters)



TO-92 Ammo-Pack Outline (Dimensions in millimeters)

